

Technical Data Data Sheet N1449, Rev. A Green Products

## **BZT52C2V4S SERIES ZENER DIODES**

#### Features:

- Planar Die Construction
- 200mW Power Dissipation
- General purpose, medium current
- Ideally suited for automated assembly processes
- Available in lead free version

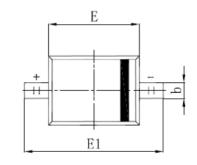
#### **Mechanical Data:**

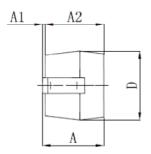
• Case: SOD-323, Molded Plastic

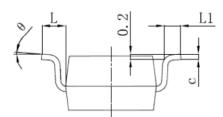
• Terminals: Solderable per MIL-STD-750, Method 2026

Polarity: Cathode Band
Weight: 0.008 grams (approx.)
Mounting Position: Any

## **Mechanical Dimensions: In Inches / mm**







Symbol	Dimensions	In Millimeters	Dimensions In Inches				
Symbol	Min.	Max.	Min.	Max.			
Α		1.000		0.039			
A 1	0.000	0.100	0.000	0.004			
A 2	0.800	0.900	0.031	0.035			
b	0.250	0.350	0.010	0.014			
С	0.080	0.150	0.003	0.006			
D	1.200	1.400	0.047	0.055			
E	1.600	1.800	0.063	0.071			
E1	2.500	2.700	0.098	0.106			
L	0.475	REF.	0.019 REF.				
L1	0.250	0.400	0.010	0.016			
θ	0°	8°	0°	8°			

**SOD-323** 

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •





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# **Marking Diagram:**



WX = Marking code

BZT52-C2V4S

Cautions: Molding resin

Epoxy resin UL: 94V-0

# **Ordering Information:**

Device	Package	Shipping
BZT52C2V4S-BZT52C51S	SOD-323 (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

## Maximum Ratings (Ta=25°C, Unless otherwise specified)

Characteristic	Symbol	BZT52C2V4S-BZT52C51S	Unit
Forward Voltage (Note 2) @ I <sub>F</sub> = 10mA	V <sub>F</sub>	0.9	V
Power Dissipation (Note 1) @T <sub>A</sub> = 25°C	Po	200	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	625	°C/W
Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

Note: 1 Mounted on 5.0mm 2 (.013mm thick) land areas.

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# **BZT52C2V4S-BZT52C51S**

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## Green Products

TYPE	Marking	Zener Voltage Range (Note 2)			Maximum Zener Impedance (Note 3)			Maximum Reverse Current (Note 2)		Typical Temperature Coefficient @  <sub>ZTC</sub> mV/C		Test Current Izrc	
			Vz@lzt		I <sub>ZT</sub>	Z <sub>zt</sub> @l <sub>zt</sub>	T Z <sub>zk</sub> @l <sub>zk</sub> I <sub>zk</sub>		I <sub>R</sub> V <sub>R</sub>				
		Nom(V)	Min(V)	Max(V)	(mA)	!	Ω	(mA)	μА	V	Min	Max	mA
BZT52C2V4S	VVX	2.4	2.20	2.60	5	100	600	1.0	50	1.0	-3.5	0	5
BZT52C2V7S	VVI	2.7	2.5	2.9	5	100	600	1.0	20	1.0	-3.5	0	5
BZT52C3V0S	W2	3.0	2.8	3.2	5	95	600	1.0	10	1.0	-3.5	0	5
BZT52C3V3S	W8	3.3	3.1	3.5	5	95	600	1.0	5	1.0	-3.5	0	5
BZT52C3V6S	V\4	3.6	3.4	3.8	5	90	600	1.0	5	1.0	-3.5	0	5
BZT52C3V9S	V\5	3.9	3.7	4.1	5	90	600	1.0	3	1.0	-3.5	0	5
BZT52C4V3S	V\6	4.3	4.0	4.6	5	90	600	1.0	3	1.0	-3.5	0	5
BZT52C4V7S	W7	4.7	4.4	5.0	5	80	500	1.0	3	2.0	-3.5	0.2	5
BZT52C5V1S	V/8	5.1	4.8	5.4	5	60	480	1.0	2	2.0	-2.7	1.2	5
BZT52C5V6S	W9	5.6	5.2	6.0	5	40	400	1.0	1	2.0	-2	2.5	5
BZT52C6V2S	WA	6.2	5.8	6.6	5	10	150	1.0	3	4.0	0.4	3.7	5
BZT52C6V8S	WB	6.8	6.4	7.2	5	15	80	1.0	2	4.0	1.2	4.5	5
BZT52C7V5S	WC	7.5	7.0	7.9	5	15	80	1.0	1	5.0	2.5	5.3	5
BZT52C8V2S	WD	8.2	7.7	8.7	5	15	80	1.0	0.7	5.0	3.2	6.2	5
BZT52C9V1S	WE	9.1	8.5	9.6	5	15	100	1.0	0.5	6.0	3.8	7.0	5
BZT52C10S	WF	10	9.4	10.6	5	20	150	1.0	0.2	7.0	4.5	8.0	5
BZT52C11S	WG	11	10.4	11.6	5	20	150	1.0	0.1	8.0	5.4	9.0	5
BZT52C12S	WH	12	11.4	12.7	5	25	150	1.0	0.1	8.0	6.0	10.0	5
BZT52C13S	W	13	12.4	14.1	5	30	170	1.0	0.1	8.0	7.0	11.0	5
BZT52C15S	WJ	15	13.8	15.6	5	30	200	1.0	0.1	10.5	9.2	13	5
BZT52C16S	WK	16	15.3	17.1	5	40	200	1.0	0.1	11.2	10.4	14	5
BZT52C18S	WL	18	16.8	19.1	5	45	225	1.0	0.1	12.6	12.4	16	5
BZT52C20S	VVM	20	18.8	21.2	5	55	225	1.0	0.1	14.0	14.4	18.0	5
BZT52C22S	WN	22	20.8	23.3	5	55	250	1.0	0.1	15.4	16.4	20.0	5
BZT52C24S	WO	24	22.8	25.6	5	70	250	1.0	0.1	16.8	18.4	22.0	5
BZT52C27S	WP	27	25.1	28.9	2	80	300	0.5	0.1	18.9	21.4	25.3	2
BZT52C30S	WQ	30	28.0	32.0	2	80	300	0.5	0.1	21.0	24.4	29.4	2
BZT52C33S	WR	33	31.0	35.0	2	80	325	0.5	0.1	23.1	27.4	33.4	2
BZT52C36S	WS	36	34.0	38.0	2	90	350	0.5	0.1	25.2	30.4	37.4	2
BZT52C39S	WT	39	37.0	41.0	2	130	350	0.5	0.1	27.3	33.4	41.2	2
BZT52C43S	WU	43	40.0	46.0	2	100	700	1	0.1	32	10	12	5

Notes: 1. Device mounted on ceramic PCB: 7.6mm x 9.4mm x 0.87mm with pad areas 25mm<sup>2</sup>.

• China - Germany - Korea - Singapore - United States •

Short duration test pulse used to minimize self-heating effect.
 f = 1kHz.

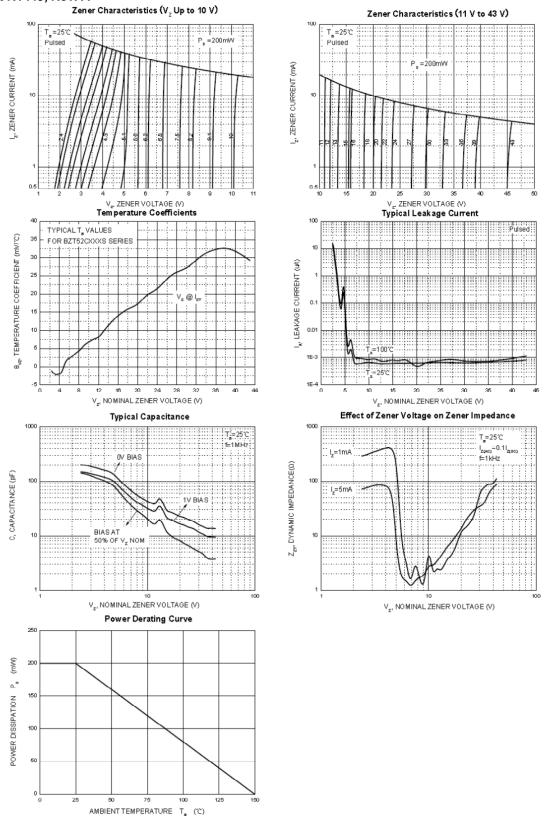
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Green Products

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